

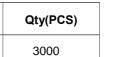
Features

Collector Current: I_C= -0.1A

Power Dissipation of 200mW

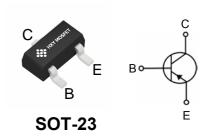
Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
BC856/BC857/ BC858	SOT-23	3x	3000



x:BC856A=A; BC856B=B;

BC857A=E; BC857B=F; BC857C=G; BC858A=J; BC858B=K; BC858C=L.



Maximum Ratings (Ta=25°C unless otherwise noted)

Symbl	Parameter		Value	Unit
		BC856	-80	
Vсво	Collector-Base Voltage	BC857	-50	V
		BC858	-30	
		BC856	- 65	
VCEO	Collector-Emitter Voltage	BC857	- 45	V
		BC858	-30	
Vево	Emitter-Base Voltage		-5	V
Ic	Collector Current-Continuous		-0.1	Α
Pc	Collector Power Dissipation		200	mW
T _j	Junction Temperature		150	ပ
T _{stg}	Storage Temperature		-55-150	$^{\circ}$

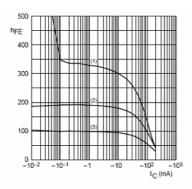


Electrical Characteristics (Ta=25°C unless otherwise specified)

Parameter		Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown vo	oltage BC856		-80			
	BC857	VCBO	IC= -10μA, IE=0	-50		V
	BC858			-30		
Collector-emitter breakdov	vn voltage			-65		
BC856 BC857 BC858		VCEO	IC= -10mA, IB=0	-45		V
				-30		
Emitter-base breakdown volt	age	VEBO	IE= -1μΑ, IC=0	-5		V
Collector cut-off current	BC856	ICBO	VCB= -70 V , IE=0			
	BC857		VCB= -45 V , IE=0		-0.5	μΑ
	BC858		VCB= -25 V , IE=0			
Collector cut-off current	BC856		VCE= -60 V , IB=0			
	BC857	ICEO	VCE= -40 V , IB=0		-0.5	μA
	BC858		VCE= -25 V , IB=0			
Emitter cut-off current		IEBO	VEB= -5 V , IC=0		-0.1	μA
DC current gain	BC856A,857A,858A			125	250	
	BC856B,857B,858B	hFE	VCE= -5V, IC= -2mA	220	475	
	BC857C,BC858C			420	800	
Collector-emitter saturation v	llector-emitter saturation voltage VCE(sat) IC=-100mA, IB= -5 mA			-0.5	V	
Base-emitter saturation volta	Base-emitter saturation voltage		IC= -100mA, IB= -5mA		-1.1	V
		fT	VCE= -5 V, IC=	100		MHz
Transition frequency			-10mA f=100MHz			
Collector capacitance		Cob	VCB=-10V, f=1MHz		4.5	pF

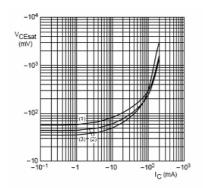


Typical Characteristics



BC857A; V_{CE} = -5 V. (1) T_{amb} = 150 °C. (2) T_{amb} = 25 °C. (3) T_{amb} = -55 °C.

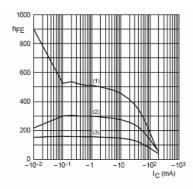
Fig.2 DC current gain as a function of collector current; typical values.



BC857A; I_C/I_B = 20. (1) T_{amb} = 150 °C. (2) T_{amb} = 25 °C.

(3) T_{amb} = −55 °C.

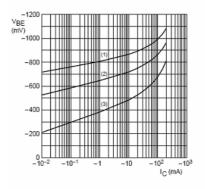
Fig.4 Collector-emitter saturation voltage as a function of collector current; typical values



BC857B; V_{CE} = -5 V. (1) T_{amb} = 150 °C. (2) T_{amb} = 25 °C.

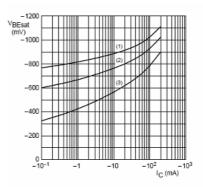
(3) T_{amb} = -55 °C.

Fig.6 DC current gain as a function of collector current; typical values.



BC857A; V_{CE} = -5 V. (1) T_{amb} = -55 °C. (2) T_{amb} = 25 °C. (3) T_{amb} = 150 °C.

Fig.3 Base-emitter voltage as a function of collector current; typical values.

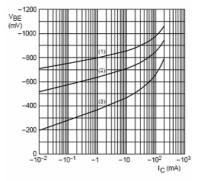


BC857A; I_C/I_B = 20

(1) T_{amb} = -55 °C. (2) T_{amb} = 25 °C.

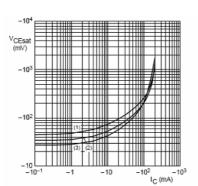
(3) T_{amb} = 150 °C.

Fig.5 Base-emitter saturation voltage as a function of collector current; typical values.



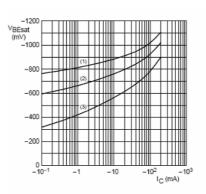
BC857B; V_{CE} = -5 V. (1) T_{amb} = -55 °C. (2) T_{amb} = 25 °C. (3) T_{amb} = 150 °C.

Fig.7 Base-emitter voltage as a function of collector current; typical values.



BC857B; I_C/I_B = 20. (1) T_{amb} = 150 °C. (2) T_{amb} = 25 °C. (3) T_{amb} = -55 °C.

Fig.8 Collector-emitter saturation voltage as a function of collector current; typical values.



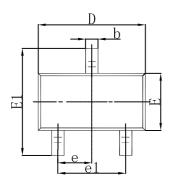
BC857B; I_O/I_B = 20. (1) T_{amb} = -55 °C. (2) T_{amb} = 25 °C. (3) T_{amb} = 150 °C.

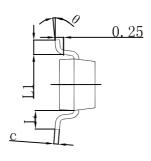
Fig.9 Base-emitter saturation voltage as a function of collector current; typical values.

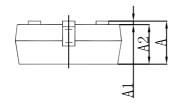


Package Dimensions

SOT-23

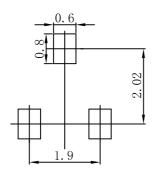






Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950	TYP	0.037 TYP		
e1	1.800	2.000	0.071	0.079	
L	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

Suggested Pad Layout



- Note: 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.

BC856/BC857/BC858 PNP Plastic-Encapsulate Transistors

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